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Inclosure Material:

Metal all semiconductor device diode

Overall Length:

0.070 inches

End Application:

Wgu-2c/b guid e/i fscm 96214

Component Function Relationship:

Matched

Component Name And Quantity:

4 semiconductor device diode

Mounting Method:

Terminal all semiconductor device diode

Field Force Effect Type:

Electrostatic charge

Semiconductor Material:

Silicon all semiconductor device diode

Voltage Rating In Volts Per Characteristic:

0.390 forward voltage, dc all semiconductor device diode

Power Rating Per Characteristic:

0.5 watts small-signal output power, common-base megawatts all semiconductor device diode

Capacitance Rating In Picofarads:

0.17 all semiconductor device diode

Maximum Operating Temperature Per Measurement Point:

150.0 degrees celsius junction all semiconductor device diode

Special Features:

Component shall consist of a set of four diodes with forward voltages matched within +/- 3.0 millivolts at 10.0 milliamperes

Precious Material And Location:

Terminals gold

Precious Material:

Gold

Terminal Type And Quantity:

2 tab, solder lug all semiconductor device diode

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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